# MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

# Monolithic Dual Switching Diodes

#### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS (EACH DIODE)**

Rating	Symbol	Value	Unit
Reverse Voltage MMBD2835LT1G, SMMBD2835LT1G MMBD2836LT1G	V <sub>R</sub>	35 75	Vdc
Forward Current	١ <sub>F</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$ Derate above 25°C	PD	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

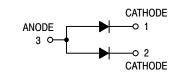


### **ON Semiconductor®**

www.onsemi.com



CASE 318-08 STYLE 12



#### MARKING DIAGRAM



xxx = Specific Device Code A3X = MMBD2835LT1G SMMBD2835LT1G A2X = MMBD2836LT1G

M = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBD2835LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SMMBD2835LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBD2836LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

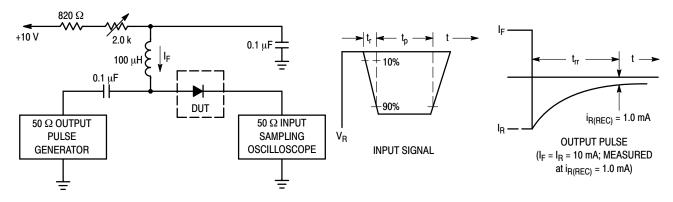
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Breakdown Voltage (I <sub>R</sub> = 100 μAdc) MMBD2835LT1G, SMMBD2835LT1G MMBD2836LT1G	V <sub>(BR)</sub>	35 75		Vdc
Reverse Voltage Leakage Current (Note 3) $(V_R = 30 \text{ Vdc})$ MMBD2835LT1G, SMMBD2835LT1G $(V_R = 50 \text{ Vdc})$	I <sub>R</sub>	-	100	nAdc
MMBD2836LT1G		-	100	
Diode Capacitance (V <sub>R</sub> = 0 V, f = 1.0 MHz)	CT	-	4.0	pF
Forward Voltage $(I_F = 10 \text{ mAdc})$ $(I_F = 50 \text{ mAdc})$ $(I_F = 100 \text{ mAdc})$	VF		1.0 1.0 1.2	Vdc
Reverse Recovery Time ( $I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}$ ) (Figure 1)	t <sub>rr</sub>	-	4.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. For each individual diode while the second diode is unbiased.



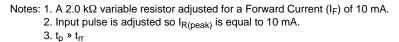


Figure 1. Recovery Time Equivalent Test Circuit

## MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

#### 100 10 $T_A=150^\circ C$ IF, FORWARD CURRENT (mA) $T_A = 85^{\circ}C$ IR, REVERSE CURRENT (µA) T<sub>A</sub> = 125°C = −40°C TA 1.0 10 $T_A = 85^{\circ}C$ 0.1 $T_A = 25^{\circ}C$ 1.0 $T_A = 55^{\circ}C$ 0.01 T<sub>A</sub> = 25°C : 0.1 0.001 0.2 1.0 1.2 0 10 0.6 0.8 30 0.4 20 40 50 V<sub>F</sub>, FORWARD VOLTAGE (VOLTS) V<sub>R</sub>, REVERSE VOLTAGE (VOLTS)

### **CURVES APPLICABLE TO EACH CATHODE**



Figure 3. Leakage Current

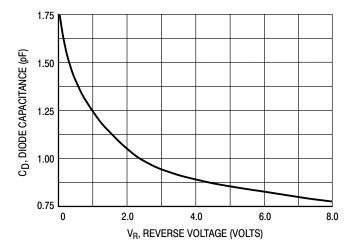
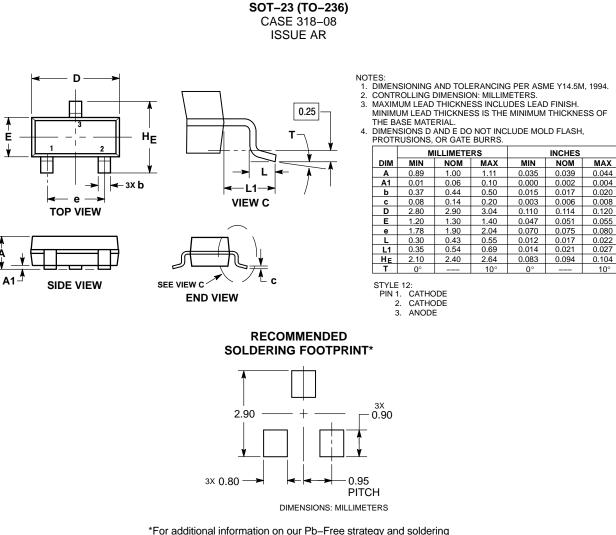


Figure 4. Capacitance

#### MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

#### PACKAGE DIMENSIONS



details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns me rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor asy products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application. Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufac

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative